

# NCE N-Channel Enhancement Mode Power MOSFET

# **Description**

The NCE82H160D uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

•  $V_{DS} = 82V, I_D = 160A$  $R_{DS(ON)} < 4.5mΩ @ V_{GS} = 10V$  (Typ:3.6mΩ)

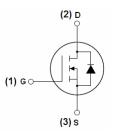
- Special process technology for high ESD capability
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation

#### **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!



#### Schematic diagram



Marking and pin assignment



TO-263-2L top view

#### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE82H160D	NCE82H160D	TO-263-2L	-	-	-

Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	82	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	160	Α
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	113	Α
Pulsed Drain Current	I <sub>DM</sub>	640	А
Maximum Power Dissipation	P <sub>D</sub>	285	W
Derating factor		1.9	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	1656	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$ C



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# **NCE82H160D**

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2)	R <sub>eJc</sub>	0.53	°C/W	Ī
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# Electrical Characteristics (T<sub>C</sub>=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	82	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =82V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2	3	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	3.6	4.5	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	75	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ 40\/\/ 0\/	-	11180	-	PF
Output Capacitance	Coss	$V_{DS}$ =40V, $V_{GS}$ =0V, F=1.0MHz	-	537	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	r=1.0lvln2	-	461	-	PF
Switching Characteristics (Note 4)			•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	30	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =40V, $R_L$ =2 $\Omega$	-	48	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{GEN}$ =2.5 $\Omega$	-	82	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	35	-	nS
Total Gate Charge	Qg	\/ -40\/ L -20A	-	201	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =40V, $I_{D}$ =20A, $V_{GS}$ =10V	-	47	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	60	-	nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =160A	-	-	1.2	V
Diode Forward Current (Note 2)	Is	-	-	-	160	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 20A	-	70	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	140	-	nC

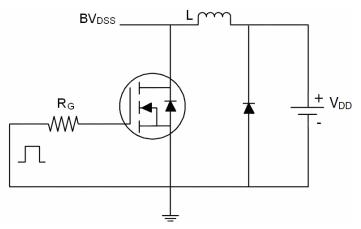
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition: Tj=25 $^{\circ}$ C,VDD=40V,VG=10V,L=0.5mH,Rg=25 $\Omega$

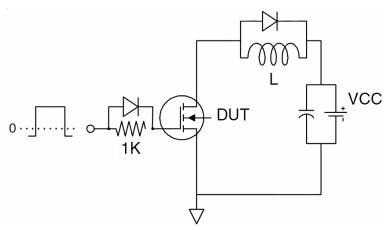


# **Test circuit**

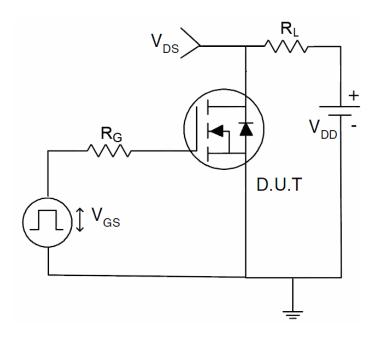
# 1) E<sub>AS</sub> test Circuit



# 2) Gate charge test Circuit

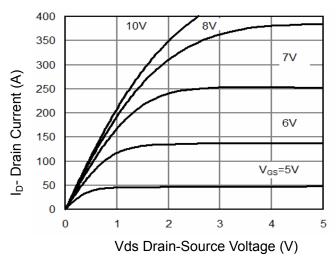


### 3) Switch Time Test Circuit

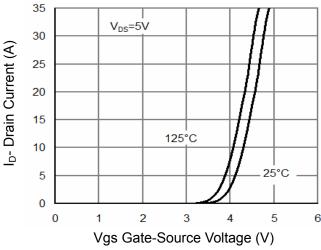




# **Typical Electrical and Thermal Characteristics (Curves)**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

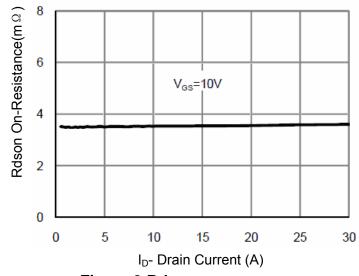


Figure 3 Rdson- Drain Current

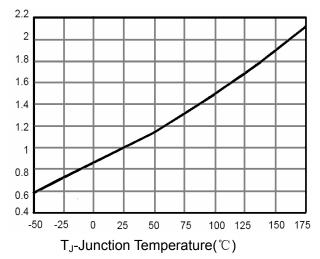


Figure 4 Rdson-JunctionTemperature

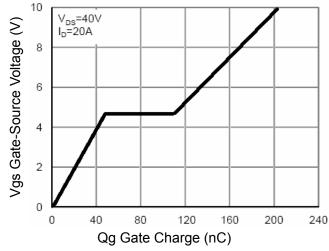


Figure 5 Gate Charge

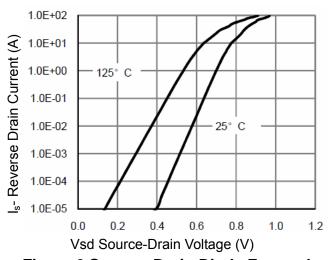
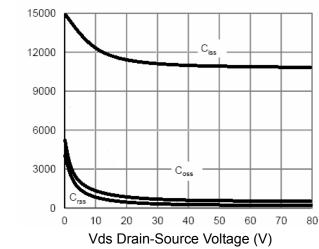


Figure 6 Source- Drain Diode Forward



C Capacitance (pF)



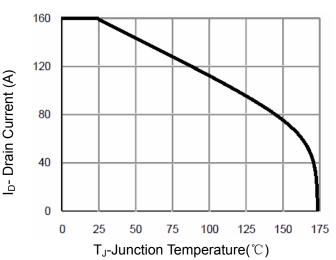
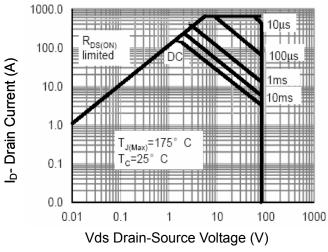
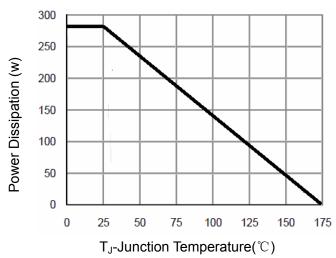


Figure 7 Capacitance vs Vds

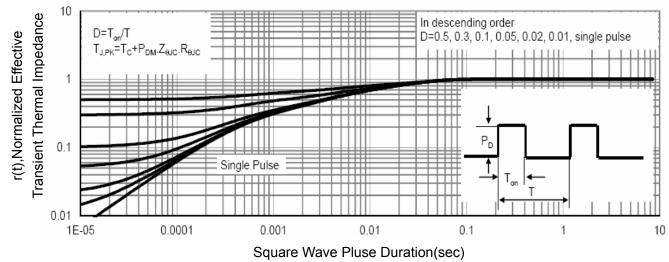
Figure 9 Current De-rating





**Figure 8 Safe Operation Area** 

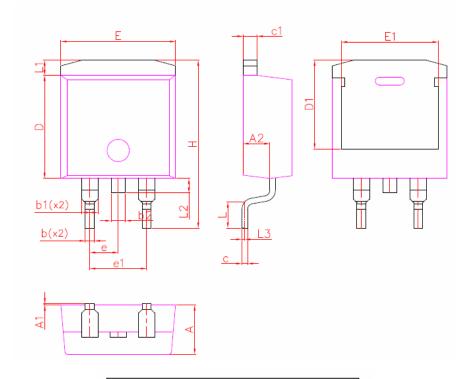
Figure 10 Power De-rating



**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# **TO-263-2L Package Information**



TO263				
DIM.	MIN.	NOM.	MAX.	
Α	4.20	4.40	4.60	
A1	0.00	0.10	0.25	
A2	2.20	2.40	2.60	
b	0.70	0.80	0.90	
b1	1.20	1.45	1.75	
b2	1.17	1.27	1.37	
С	0.40	0.50	0.60	
с1	1.15	1.27	1.40	
D	9.10	9.20	9.30	
D1	7.63	7.93	8.23	
Е	10.05	10.25	10.45	
E1	8.35	8.65	8.95	
е	2.54BSC			
e1	5.08BSC			
Н	14.61	15.00	15.88	
L	1.78	2.35	2.79	
L1	1.36REF			
L2	1.3REF			
L3	0.25REF			
All dimensions in millimeters				

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# NCE82H160D

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